

Typical Applications

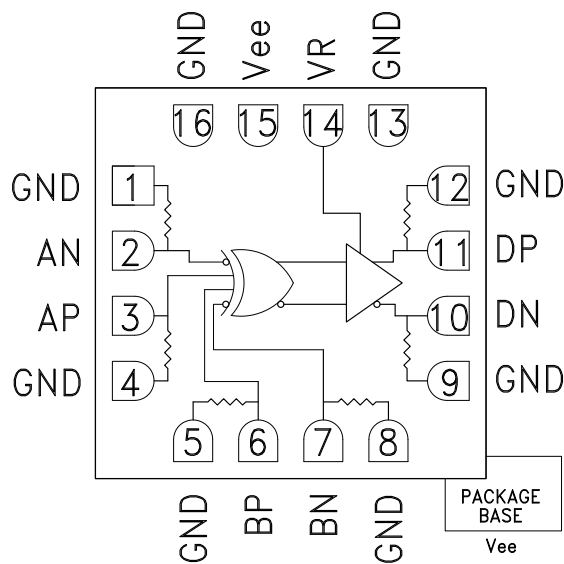
The HMC671LC3C is ideal for:

- RF ATE Applications
- Broadband Test & Measurement
- Serial Data Transmission up to 13 Gbps
- Digital Logic Systems up to 13 GHz

Features

- Inputs Terminated Internally in 50 Ohms
- Differential & Single-Ended Operation
- Fast Rise and Fall Times: 24 / 22 ps
- Low Power Consumption: 180 mW typ.
- Programmable Differential
Output Voltage Swing: 400 - 1100 mV
- Propagation Delay: 60 ps
- Single Supply: -3.3V
- 16 Lead Ceramic 3x3mm SMT Package: 9mm²

Functional Diagram



General Description

The HMC671LC3C is a XOR/XNOR gate function designed to support data transmission rates of up to 13 Gbps, and clock frequencies as high as 13 GHz. All input signals to the HMC671LC3C are terminated with 50 Ohms to ground on-chip, and maybe either AC or DC coupled. The differential outputs of the HMC671LC3C may be either AC or DC coupled. Outputs can be connected directly to a 50 Ohm to ground terminated system, while DC blocking capacitors may be used if the terminating system is 50 Ohms to a non-ground DC voltage. The HMC671LC3C operates from a single -3.3V DC supply, dissipates only 180 mW, and is available in a ceramic RoHS compliant 3x3 mm SMT package.

Electrical Specifications, $T_A = +25\text{ }^\circ\text{C}$, $V_{ee} = -3.3\text{V}$

Parameter	Conditions	Min.	Typ.	Max	Units
Power Supply Voltage		-3.6	-3.3	-3.0	V
Power Supply Current			55		mA
Maximum Data Rate			13		Gbps
Maximum Clock Rate			13		GHz
Clock Bandwidth, 3 dB	200 mVp-p Input		12.2		GHz
Input High Voltage		-0.5		0.5	V
Input Low Voltage		-1.0		0.0	V
Input Return Loss	Frequency <13 GHz		10		dB
Output Amplitude	Single-Ended, peak-to-peak		550		mVp-p
	Differential, peak-to-peak		1100		mVp-p
Output High Voltage			-10		mV
Output Low Voltage			-570		mV



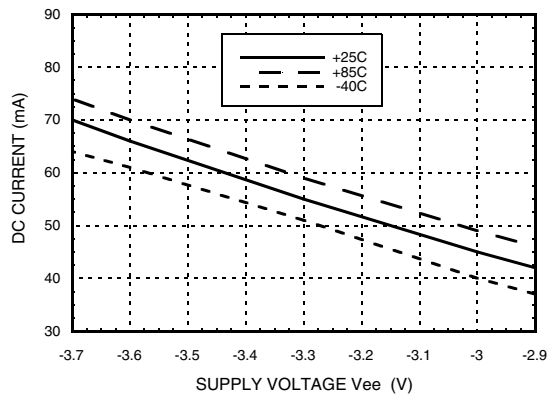
Electrical Specifications, (continued)

Parameter	Conditions	Min.	Typ.	Max	Units
Output Rise / Fall Time	Differential, 20% - 80%		24 / 22		ps
Output Return Loss	Frequency <13 GHz		10		dB
Small Signal Gain			27		dB
Random Jitter Jr	rms ^[1]			0.2	ps rms
Deterministic Jitter, Jd	peak-to-peak, 2 ¹⁵ -1 PRBS input ^[2]		2		ps, p-p
Propagation Delay, td			60		ps

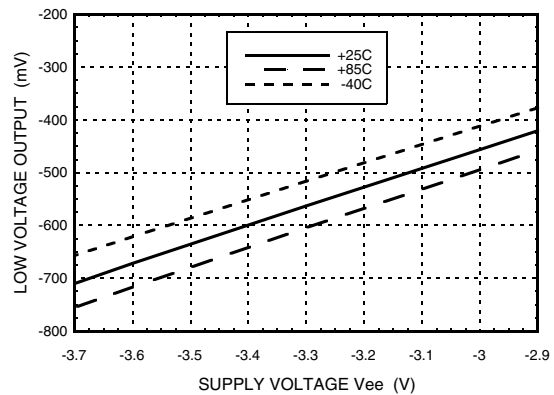
[1] Upper limit of random jitter, JR, determined by measuring and integrating output phase noise with a sinusoidal input at 5, 10, and 13.5 GHz over temperature

[2] Deterministic jitter calculated by simultaneously measuring the jitter of a 200 mV, 12.5 GHz, 2¹⁵-1 PRBS input, and a single-ended output

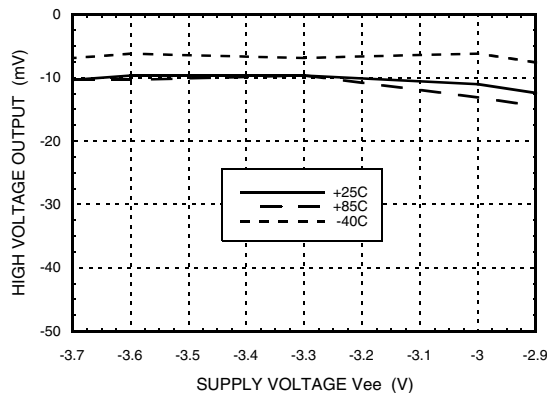
DC Current vs. Supply Voltage^[1]



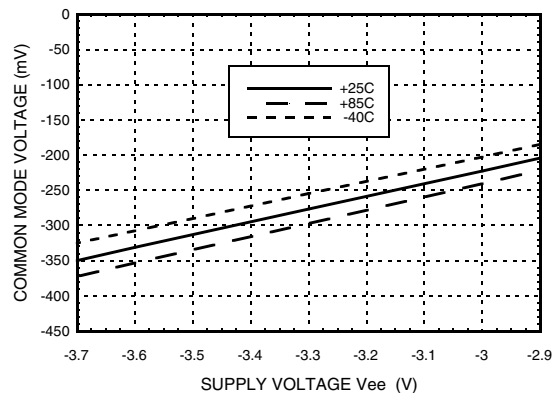
Output Low Voltage vs. Supply Voltage^{[1] [2]}



Output High Voltage vs. Supply Voltage^{[1] [2]}



Common Mode Voltage vs. Supply Voltage^{[1] [2]}

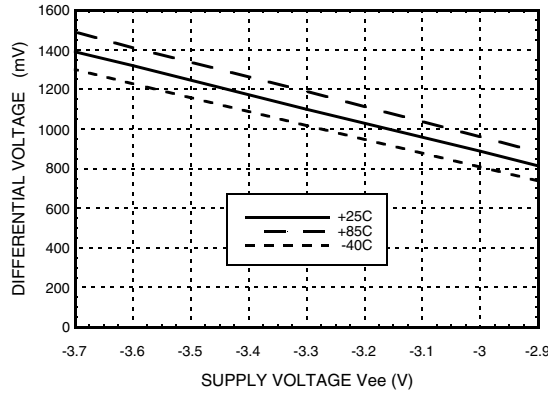


[1] VR = 0.0V

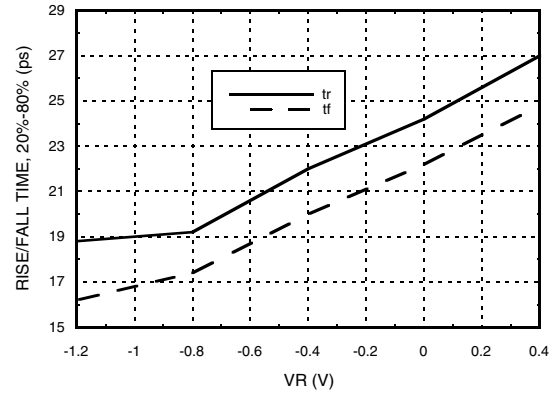
[2] Frequency = 1 GHz



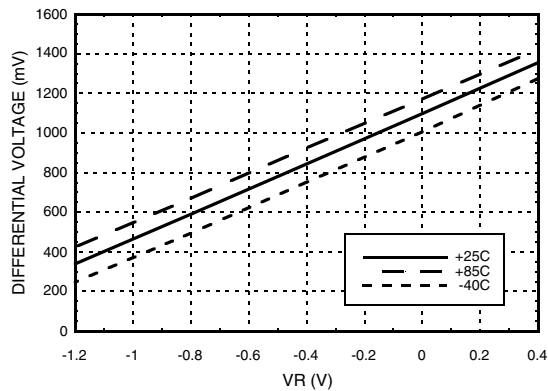
Output Differential vs. Supply Voltage [1] [2]



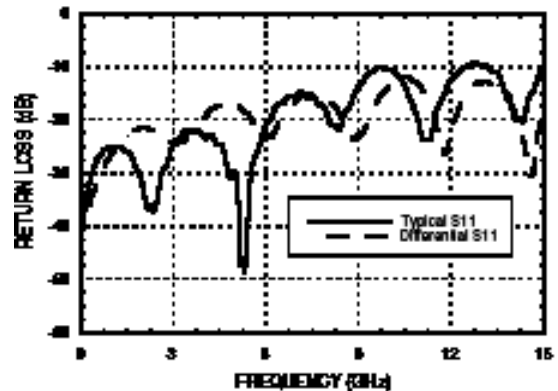
Rise / Fall Time vs. VR [3]



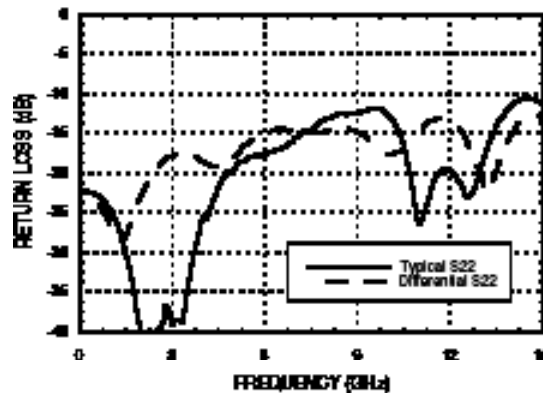
Output Differential vs. VR [2]



Input Return Loss vs. Frequency



Output Return Loss vs. Frequency

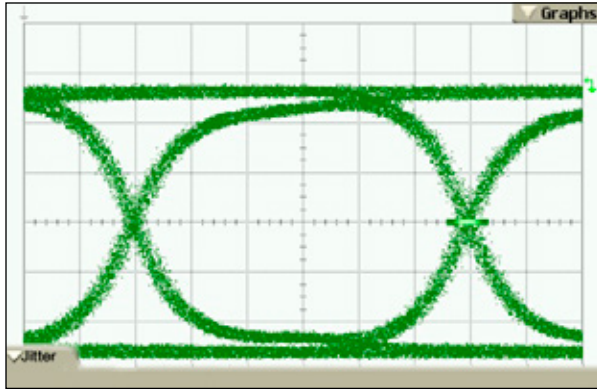


[1] VR = 0.0V

[2] Frequency = 1 GHz

[3] Frequency = 5 GHz

Eye Diagram

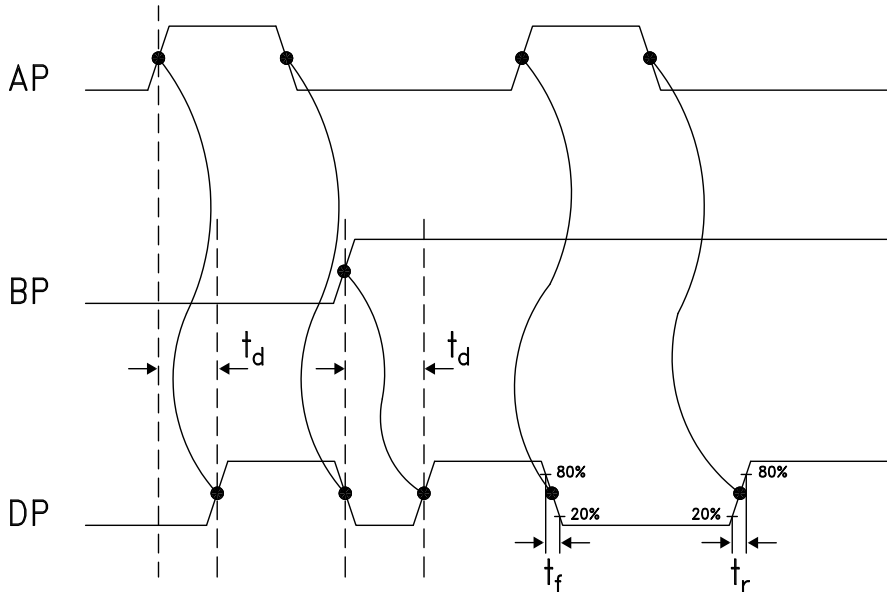


Parameter	Conditions
Bit Rate	10.00000 Gbps
Pattern Length	32767 Bits
DJ (δ - δ)	5.4 ps
Vertical Scale	100 mV / div
Time Scale	16.7 ps / div

[1] Test Conditions:
 Pattern generated with an Agilent N4901B Serial BERT
 Eye diagram data presented on an Infinium DCA 86100A
 Rate = 10.0 GB/s
 Pseudo Random Code = $2^{15} - 1$
 Vin = 400 mVp-p differential

[2] Vertical Scale = 100 mV/Div

Timing Diagram



Truth Table

Input		Outputs
A	B	D
L	L	L
L	H	H
H	L	H
H	H	L

Notes:
 A = AP - AN
 B = BP - BN
 D = DP - DN

H - Positive voltage level
 L - Negative voltage level

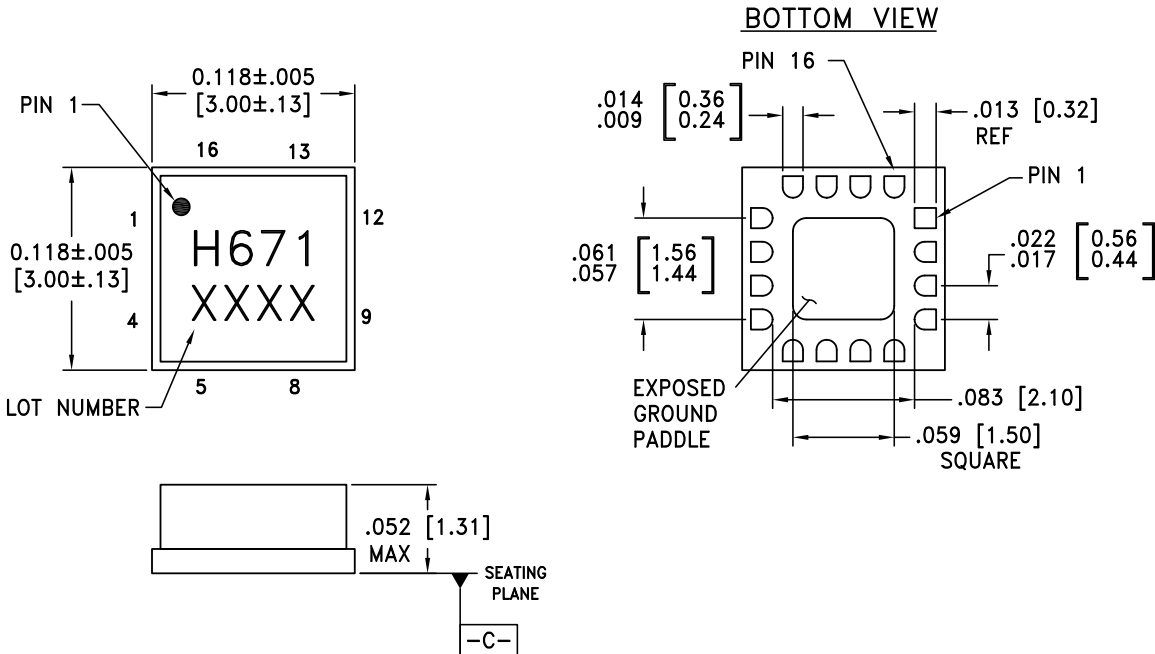
Absolute Maximum Ratings

Power Supply Voltage (Vee)	-3.75V to +0.5V
Input Signals	-2V to +0.5V
Output Signals	-1.5V to +1V
Storage Temperature	-65°C to +150°C
Operating Temperature	-40°C to +85°C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**


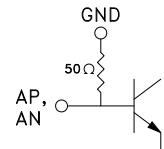
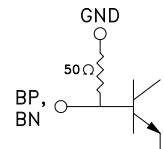
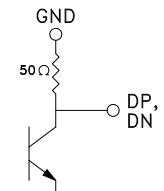

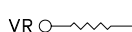
Outline Drawing



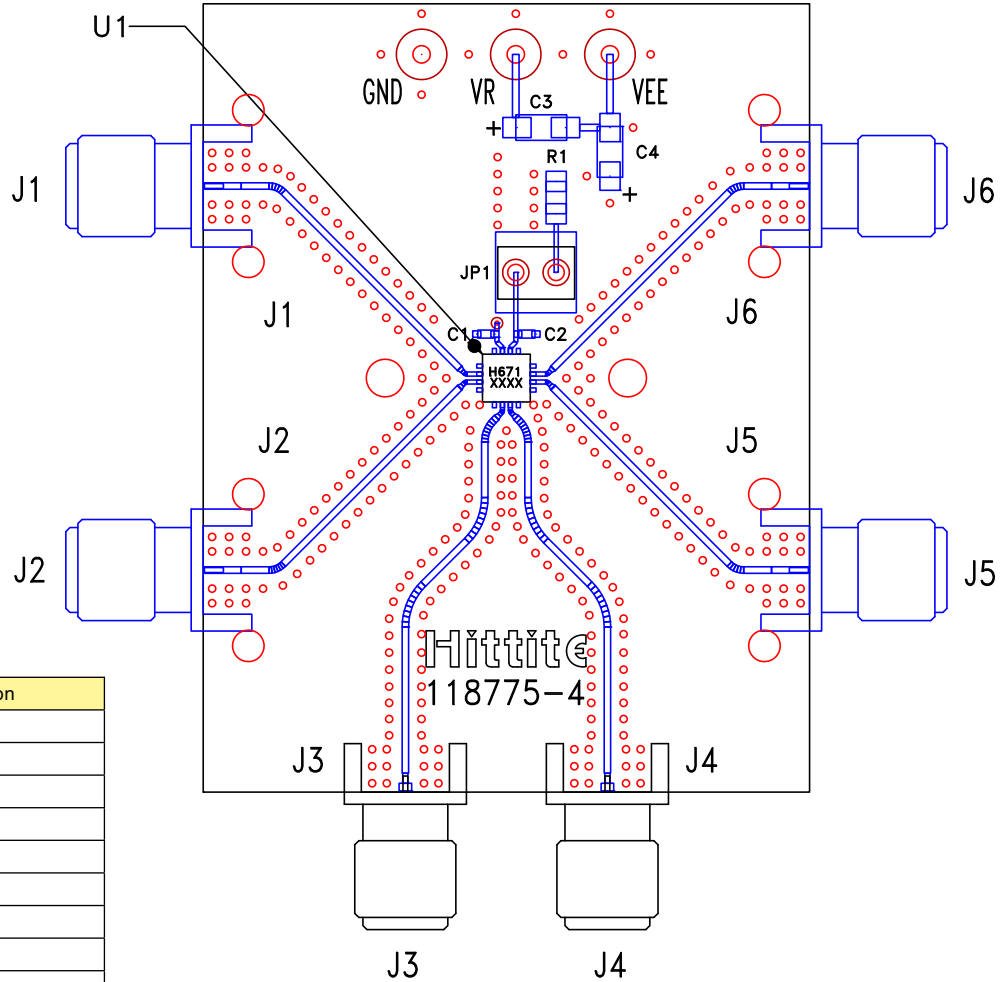
NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING:
30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
6. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
7. GROUND PADDLE MUST BE SOLDERED TO Vee.


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 5, 8, 9, 12	GND	Signal Grounds	
2, 3	AN, AP	Clock / Data Input A	
6, 7	BP, BN	Clock / Data Input B	
10, 11	DN, DP	Clock / Data Output	
13, 16	GND	Supply Ground	
14	VR	Output level control. Output level may be adjusted by either applying a voltage to VR per "Output Differential vs. VR" plot, or by tying VR to GND with a resistor per the following equation: $V_o(R) = 1.2 / (2.1 + R)$, R in k Ω	
15, Package Base	Vee	Negative Supply	

Evaluation PCB



Item	Description
J1	AN
J2	AP
J3	BP
J4	BN
J5	DN
J6	DP
J7, J8, J12 - J14	GND
J10	VR
J11	Vee

List of Materials for Evaluation PCB 118777 [1]

Item	Description
J1 - J6	PCB Mount SMA RF Connectors
J7 - J14	DC Pin
C1 - C3	10 pF Capacitor, 0402 Pkg.
C4 - C5	4.7 μF Capacitor, Tantalum
R1	10 Ohm Resistor, 0603 Pkg.
U1	HMC671LC3C High Speed Logic, XOR / XNOR
PCB [2]	118775 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. The exposed package base should be connected to Vee. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

**Application Circuit**